

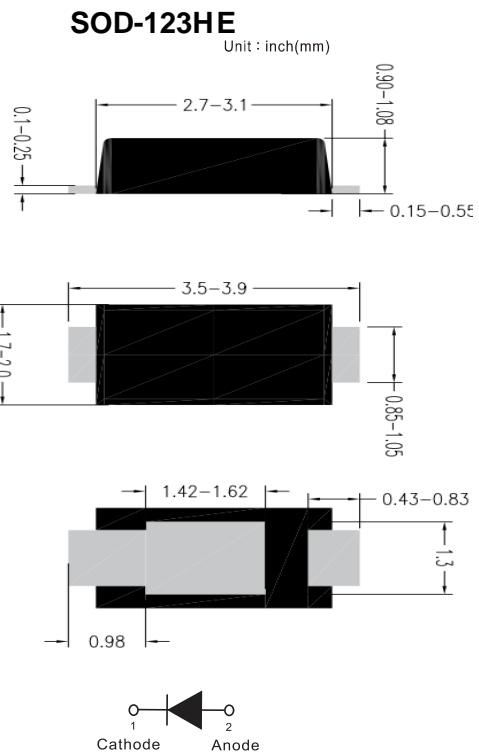
Surface Mount Schottky Rectifier

Features

- Low profile package
- Ideal for automated placement
- Guardring for overvoltage protection
- Low power losses, high efficiency
- High forward surge capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified (Automotive grade with suffix "Q".)
- Expsemi electronics

Typical Applications

For use in low voltage high frequency inverters, freewheeling, DC/DC converters, and polarity protection applications.



Mechanical Data

- **Package:** SOD-123HE
Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant, halogen-free
- **Terminals:** Tin plated leads, solderable per J-STD-002 and JESD22-B102
- **Polarity:** Cathode line denotes the cathode end

Maximum Ratings (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	SSD22 HE	SSD23 HE	SSD24 HE	SSD25 HE	SSD26 HE	SSD28 HE	SSD210 HE	SSD215 HE	SSD220 HE
Repetitive peak reverse voltage	VRRM	V	20	30	40	50	60	80	100	150	200
Average rectified output current @60Hz sine wave, Resistance load, Ta (FIG.1)	IO	A						2.0			
Surge(non-repetitive)forward current @60Hz half-sine wave, 1 cycle, Tj=25°C	IFSM	A						50			
Storage temperature	Tstg	°C				-55 ~+150			-55 ~+175		
Junction temperature	Tj	°C				-55 ~+150			-55 ~+175		
Typical Junction Capacitance measured at 1MHz and Applied on 4.0V.D.C	Cj	pF					165				

Electrical Characteristics (Ta=25°C Unless otherwise specified)

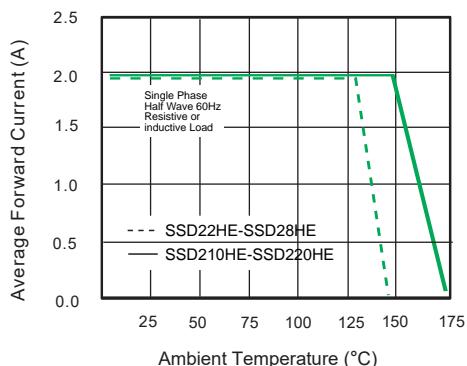
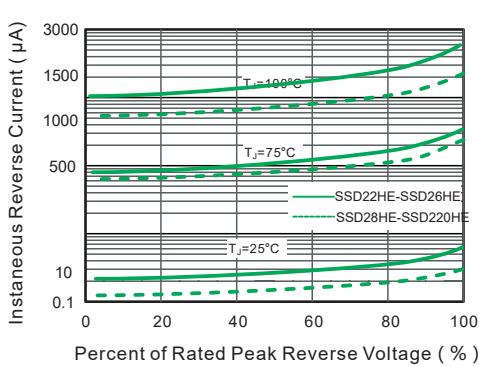
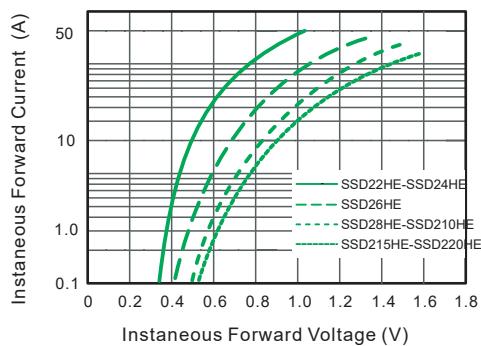
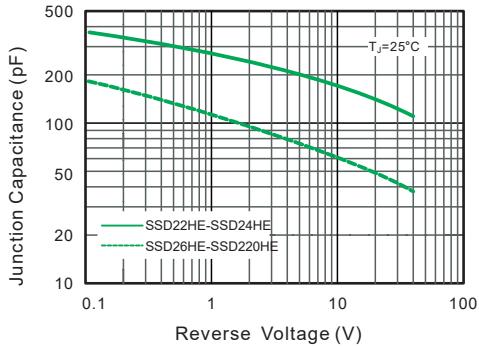
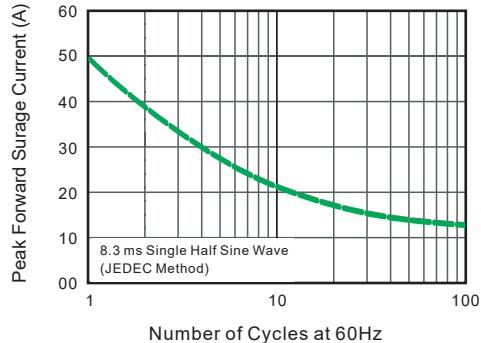
PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	SSD22 HE	SSD23 HE	SSD24 HE	SSD25 HE	SSD26 HE	SSD28 HE	SSD210 HE	SSD215 HE	SSD220 HE
Maximum instantaneous forward voltage drop per diode	VF	V	IFM=3.0A	0.55			0.7		0.78		0.9	
Maximum DC reverse current at rated DC blocking voltage per diode @ VRM=VRRM	IRRM	uA	Ta=25°C		20				5			
			Ta=100°C		200				100			

Thermal Characteristics (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	SSD22 HE	SSD23 HE	SSD24 HE	SSD25 HE	SSD26 HE	SSD28 HE	SSD210 HE	SSD215 HE	SSD220 HE
Thermal Resistance	R _{θJ-A}	°C/W									70 ¹⁾
	R _{θJ-L}										16 ¹⁾

Note:

- (1) Thermal resistance between junction and ambient and between junction and lead mounted on P.C.B with 3mm*3mm copper pad areas.

Characteristics (Typical)
Fig.1 Forward Current Derating Curve

Fig.2 Typical Reverse Characteristics

Fig.3 Typical Forward Characteristic

Fig.4 Typical Junction Capacitance

Fig.5 Maximum Non-Repetitive Peak Forward Surge Current

Fig.6- Typical Transient Thermal Impedance
